

# 8-Bit Registered Transceiver

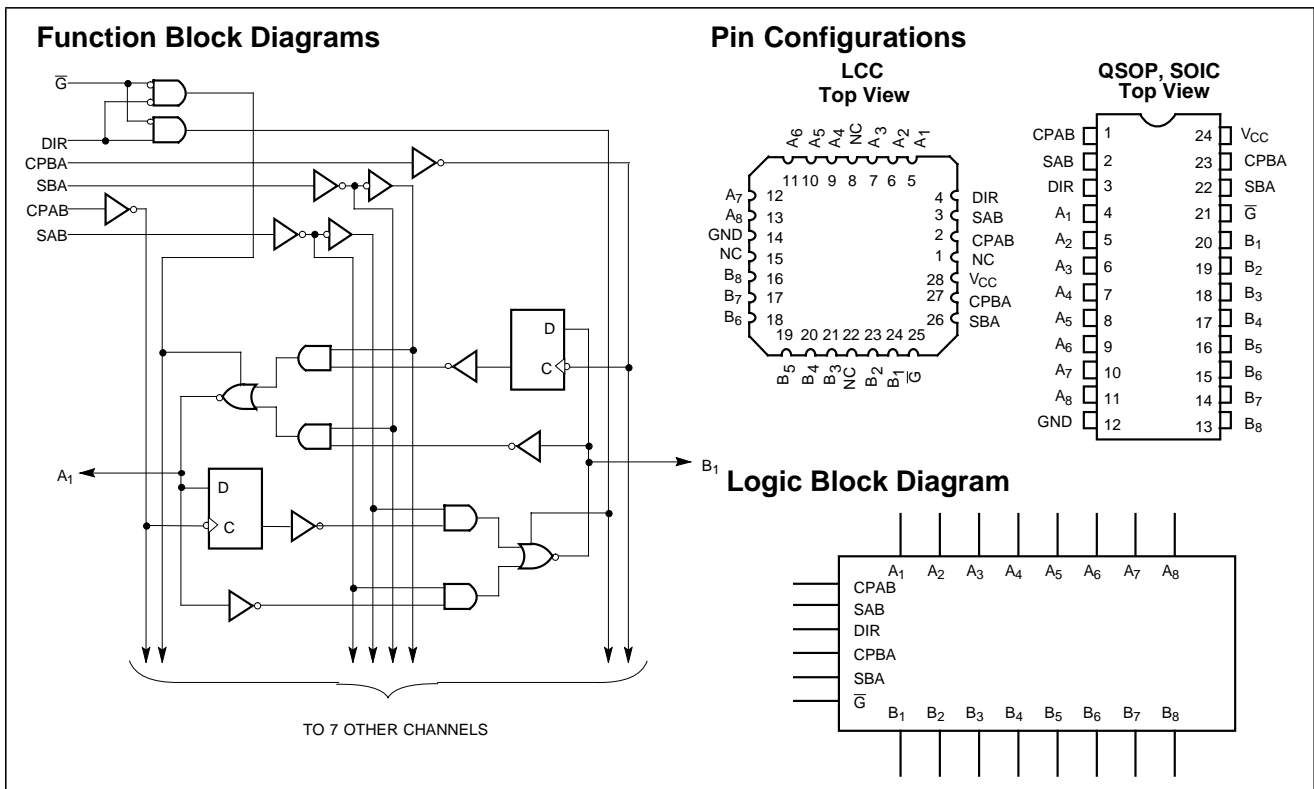
## Features

- Function, pinout, and drive compatible with FCT and F logic
- FCT-C speed at 5.4 ns max. (Com'l)  
FCT-A speed at 6.3 ns max. (Com'l)
- Reduced  $V_{OH}$  (typically = 3.3V) versions of equivalent FCT functions
- Edge-rate control circuitry for significantly improved noise characteristics
- Power-off disable feature permits live insertion
- Matched rise and fall times
- Fully compatible with TTL input and output logic levels
- ESD > 2000V
- Sink current                      64 mA (Com'l), 48 mA (Mil)
- Source current                    32 mA (Com'l), 12 mA (Mil)
- Independent register for A and B buses
- Extended commercial range of  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$

## Functional Description

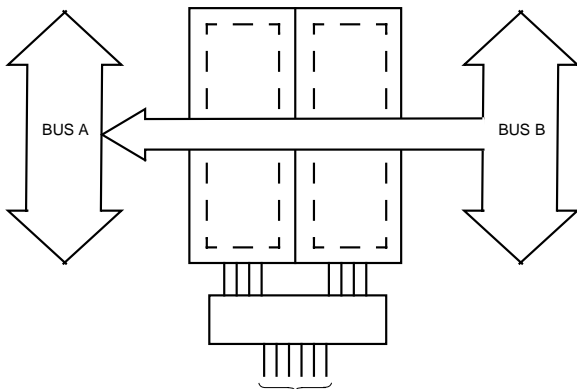
The FCT646T consists of a bus transceiver circuit with three-state, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the input bus or from the internal registers. Data on the A or B bus will be clocked into the registers as the appropriate clock pin goes to a HIGH logic level. Enable Control  $\bar{G}$  and direction pins are provided to control the transceiver function. In the transceiver mode, data present at the high-impedance port may be stored in either the A or B register, or in both. The select controls can multiplex stored and real-time (transparent mode) data. The direction control determines which bus will receive data when the enable control  $\bar{G}$  is Active LOW. In the isolation mode (enable Control  $\bar{G}$  HIGH), A data may be stored in the B register and/or B data may be stored in the A register.

The outputs of the FCT646T are designed with a power-off disable feature to allow for live insertion of boards.



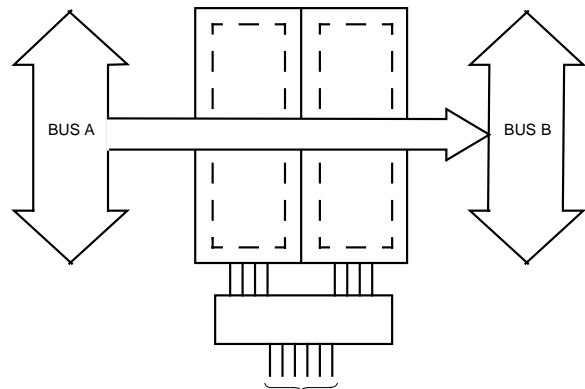
## Pin Description

Name	Description
A	Data Register A Inputs, Data Register B Outputs
B	Data Register B Inputs, Data Register A Outputs
CPAB, CPBA	Clock Pulse Inputs
SAB, SBA	Output Data Source Select Inputs
DIR, $\bar{G}$	Output Enable Inputs



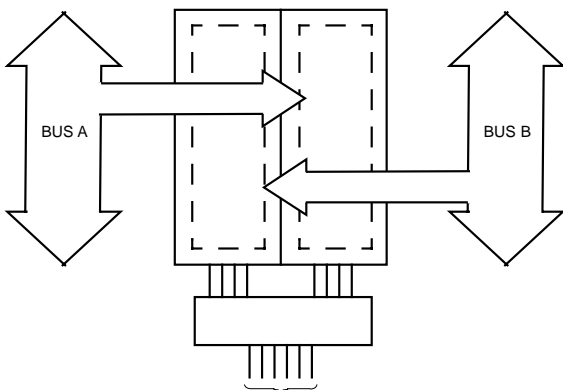
DIR L     $\bar{G}$  L    CPAB X    CPBA X    SAB X    SBA L

Real-Time Transfer  
Bus B to Bus A



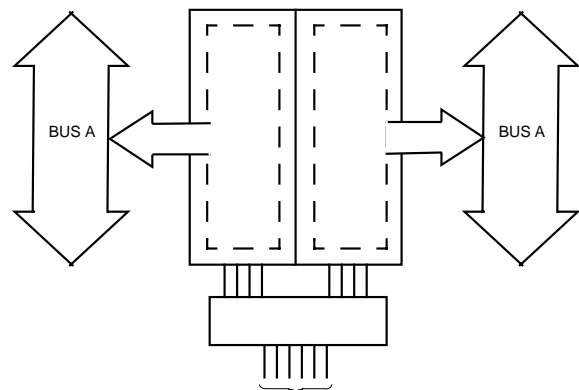
DIR H     $\bar{G}$  L    CPAB X    CPBA X    SAB L    SBA X

Real-Time Transfer  
Bus A to Bus B



DIR H L X     $\bar{G}$  L L H    CPAB  $\downarrow$  X  $\downarrow$     CPBA X  $\downarrow$  X  $\downarrow$     SAB X X X    SBA X X X

Storage from  
A and/or B



DIR<sup>[1]</sup> L H     $\bar{G}$  L L    CPAB X H or L    CPBA H or L X    SAB X H    SBA H X

Transfer Stored Data  
to A and/or B

**Function Table<sup>[2]</sup>**

Inputs						Data I/O <sup>[3]</sup>		Operation or Function
$\bar{G}$	DIR	CPAB	CPBA	SAB	SBA	A <sub>1</sub> thru A <sub>8</sub>	B <sub>1</sub> thru B <sub>8</sub>	FCT646T
H	X	H or L	H or L	X	X	Input	Input	Isolation Store A and B Data
H	X	$\downarrow$	$\downarrow$	X	X			
L	L	X	X	X	L	Output	Input	Real Time B Data to A Bus Stored B Data to A Bus
L	L	X	H or L	X	H			
L	H	X	X	L	X	Input	Output	Real Time A Data to B Bus Stored A Data to B Bus
L	H	H or L	X	H	X			

**Notes:**

1. Cannot transfer data to A bus and B bus simultaneously.
2. H = HIGH Voltage Level, L = LOW Voltage Level,  $\downarrow$  = LOW-to-HIGH Transition, X = Don't Care.
3. The data output functions may be enabled or disabled by various signals at the G or DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every LOW-to-HIGH transition of the clock inputs.

**Maximum Ratings**<sup>[4, 5]</sup>

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... -65°C to +150°C  
 Ambient Temperature with  
 Power Applied ..... -65°C to +135°C  
 Supply Voltage to Ground Potential ..... -0.5V to +7.0V  
 DC Input Voltage ..... -0.5V to +7.0V  
 DC Output Voltage ..... -0.5V to +7.0V  
 DC Output Current (Maximum Sink Current/Pin) ..... 120 mA

Power Dissipation ..... 0.5W  
 Static Discharge Voltage ..... >2001V  
 (per MIL-STD-883, Method 3015)

**Operating Range**

Range	Range	Ambient Temperature	V <sub>CC</sub>
Commercial	All	-40°C to +85°C	5V ± 5%
Military <sup>[6]</sup>	All	-55°C to +125°C	5V ± 10%

**Electrical Characteristics** Over the Operating Range

Parameter	Description	Test Conditions	Min.	Typ. <sup>[7]</sup>	Max.	Unit	
V <sub>OH</sub>	Output HIGH Voltage	V <sub>CC</sub> =Min., I <sub>OH</sub> =-32 mA	Com'l	2.0		V	
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-15 mA	Com'l	2.4	3.3	V	
		V <sub>CC</sub> =Min., I <sub>OH</sub> =-12 mA	Mil	2.4	3.3	V	
V <sub>OL</sub>	Output LOW Voltage	V <sub>CC</sub> =Min., I <sub>OL</sub> =64 mA	Com'l		0.3	0.55	V
		V <sub>CC</sub> =Min., I <sub>OL</sub> =48 mA	Mil		0.3	0.55	V
V <sub>IH</sub>	Input HIGH Voltage		2.0			V	
V <sub>IL</sub>	Input LOW Voltage				0.8	V	
V <sub>H</sub>	Hysteresis <sup>[8]</sup>	All inputs		0.2		V	
V <sub>IK</sub>	Input Clamp Diode Voltage	V <sub>CC</sub> =Min., I <sub>IN</sub> =-18 mA		-0.7	-1.2	V	
I <sub>I</sub>	Input HIGH Current	V <sub>CC</sub> =Max., V <sub>IN</sub> =V <sub>CC</sub>			5	μA	
I <sub>IH</sub>	Input HIGH Current <sup>[8]</sup>	V <sub>CC</sub> =Max., V <sub>IN</sub> =2.7V			±1	μA	
I <sub>IL</sub>	Input LOW Current <sup>[8]</sup>	V <sub>CC</sub> =Max., V <sub>IN</sub> =0.5V			±1	μA	
I <sub>OS</sub>	Output Short Circuit Current <sup>[9]</sup>	V <sub>CC</sub> =Max., V <sub>OUT</sub> =0.0V	-60	-120	-225	mA	
I <sub>OFF</sub>	Power-Off Disable	V <sub>CC</sub> =0V, V <sub>OUT</sub> =4.5V			±1	μA	

**Capacitance**<sup>[8]</sup>

Parameter	Description	Typ. <sup>[7]</sup>	Max.	Unit
C <sub>IN</sub>	Input Capacitance	6	10	pF
C <sub>OUT</sub>	Output Capacitance	8	12	pF

**Notes:**

4. Unless otherwise noted, these limits are over the operating free-air temperature range.
5. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V<sub>CC</sub> or ground.
6. T<sub>A</sub> is the "instant on" case temperature.
7. Typical values are at V<sub>CC</sub>=5.0V, T<sub>A</sub>=+25°C ambient.
8. This parameter is specified but not tested.
9. Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I<sub>OS</sub> tests should be performed last.

**Power Supply Characteristics**

Parameter	Description	Test Conditions	Typ. <sup>[7]</sup>	Max.	Unit
$I_{CC}$	Quiescent Power Supply Current	$V_{CC}=\text{Max.}, V_{IN}\leq 0.2\text{V}, V_{IN}\geq V_{CC}-0.2\text{V}$	0.1	0.2	mA
$\Delta I_{CC}$	Quiescent Power Supply Current (TTL inputs HIGH)	$V_{CC}=\text{Max.}, V_{IN}=3.4\text{V}, f_1=0, \text{Outputs Open}^{[10]}$	0.5	2.0	mA
$I_{CCD}$	Dynamic Power Supply Current <sup>[11]</sup>	$V_{CC}=\text{Max.}, \text{One Input Toggling}, 50\% \text{ Duty Cycle, Outputs Open}, \bar{G}=\text{DIR}=\text{GND}, \text{GAB}=\text{GBA}=\text{GND}, V_{IN}\leq 0.2\text{V} \text{ or } V_{IN}\geq V_{CC}-0.2\text{V}$	0.06	0.12	mA/MHz
$I_C$	Total Power Supply Current <sup>[12]</sup>	$V_{CC}=\text{Max.}, f_0=10 \text{ MHz}, 50\% \text{ Duty Cycle, Outputs Open}, \text{One Bit Toggling at } f_1=5 \text{ MHz}, \bar{G}=\text{DIR}=\text{GND}, \text{GAB}=\text{GBA}=\text{GND}, V_{IN}\leq 0.2\text{V} \text{ or } V_{IN}\geq V_{CC}-0.2\text{V}$	0.7	1.4	mA
		$V_{CC}=\text{Max.}, f_0=10 \text{ MHz}, 50\% \text{ Duty Cycle, Outputs Open}, \text{One Bit Toggling at } f_1=5 \text{ MHz}, \bar{G}=\text{DIR}=\text{GND}, \text{GAB}=\text{GBA}=\text{GND}, V_{IN}=3.4\text{V} \text{ or } V_{IN}=\text{GND}$	1.2	3.4	mA
		$V_{CC}=\text{Max.}, f_0=10 \text{ MHz}, 50\% \text{ Duty Cycle, Outputs Open}, \text{Eight Bits Toggling at } f_1=5 \text{ MHz}, \bar{G}=\text{DIR}=\text{GND}, \text{GAB}=\text{GBA}=\text{GND}, V_{IN}\leq 0.2\text{V} \text{ or } V_{IN}\geq V_{CC}-0.2\text{V}$	2.8	5.6 <sup>[13]</sup>	mA
		$V_{CC}=\text{Max.}, f_0=10 \text{ MHz}, 50\% \text{ Duty Cycle, Outputs Open}, \text{Eight Bits Toggling at } f_1=5 \text{ MHz}, \bar{G}=\text{DIR}=\text{GND}, \text{GAB}=\text{GBA}=\text{GND}, V_{IN}=3.4\text{V} \text{ or } V_{IN}=\text{GND}$	5.1	14.6 <sup>[13]</sup>	mA

**Notes:**

10. Per TTL driven input ( $V_{IN}=3.4\text{V}$ ); all other inputs at  $V_{CC}$  or GND.
11. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
12.  $I_C = I_{\text{QUIESCENT}} + I_{\text{INPUTS}} + I_{\text{DYNAMIC}}$   
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_0/2 + f_1 N_1)$   
 $I_{CC}$  = Quiescent Current with CMOS input levels  
 $\Delta I_{CC}$  = Power Supply Current for a TTL HIGH input ( $V_{IN}=3.4\text{V}$ )  
 $D_H$  = Duty Cycle for TTL inputs HIGH  
 $N_T$  = Number of TTL inputs at  $D_H$   
 $I_{CCD}$  = Dynamic Current caused by an input transition pair (HLH or LHL)  
 $f_0$  = Clock frequency for registered devices, otherwise zero  
 $f_1$  = Input signal frequency  
 $N_1$  = Number of inputs changing at  $f_1$   
 All currents are in milliamps and all frequencies are in megahertz.
13. Values for these conditions are examples of the  $I_{CC}$  formula. These limits are specified but not tested.

**Switching Characteristics** Over the Operating Range<sup>[14]</sup>

Parameter	Description	FCT646T				FCT646AT		Unit	Fig. No. <sup>[15]</sup>
		Military		Commercial		Commercial			
		Min.	Max.	Min.	Max.	Min.	Max.		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Bus to Bus	2.0	11.0	1.5	9.0	1.5	6.3	ns	1, 3
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time Enable to Bus and DIR to A <sub>n</sub> or B <sub>n</sub>	2.0	15.0	1.5	14.0	1.5	9.8	ns	1, 7, 8
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time Ḡ to Bus and DIR to Bus	2.0	11.0	1.5	9.0	1.5	6.3	ns	1, 7, 8
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Clock to Bus	2.0	10.0	1.5	9.0	1.5	6.3	ns	1, 5
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay SBA or SAB to A or B	2.0	12.0	1.5	11.0	1.5	7.7	ns	1, 5
t <sub>S</sub>	Set-Up Time HIGH or LOW, Bus to Clock	4.5		4.0		2.0		ns	4
t <sub>H</sub>	Hold Time HIGH or LOW, Bus to Clock	2.0		2.0		1.5		ns	4
t <sub>W</sub>	Pulse Width, HIGH or LOW <sup>[8]</sup>	6.0		6.0		5.0		ns	5

Parameter	Description	FCT646CT				Unit	Fig. No. <sup>[15]</sup>
		Military		Commercial			
		Min.	Max.	Min.	Max.		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Bus to Bus	1.5	6.0	1.5	5.4	ns	1, 3
t <sub>PZH</sub> t <sub>PZL</sub>	Output Enable Time Enable to Bus and DIR to A <sub>n</sub> or B <sub>n</sub>	1.5	8.9	1.5	7.8	ns	1, 7, 8
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output Disable Time Ḡ to Bus and DIR to Bus	1.5	7.7	1.5	6.3	ns	1, 7, 8
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Clock to Bus	1.5	6.3	1.5	5.7	ns	1, 5
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay SBA or SAB to A or B	1.5	7.0	1.5	6.2	ns	1, 5
t <sub>S</sub>	Set-Up Time, HIGH or LOW, Bus to Clock	2.0		2.0		ns	4
t <sub>H</sub>	Hold Time, HIGH or LOW, Bus to Clock	1.5		1.5		ns	4
t <sub>W</sub>	Pulse Width, <sup>[8]</sup> HIGH or LOW	5.0		5.0		ns	5

**Notes:**

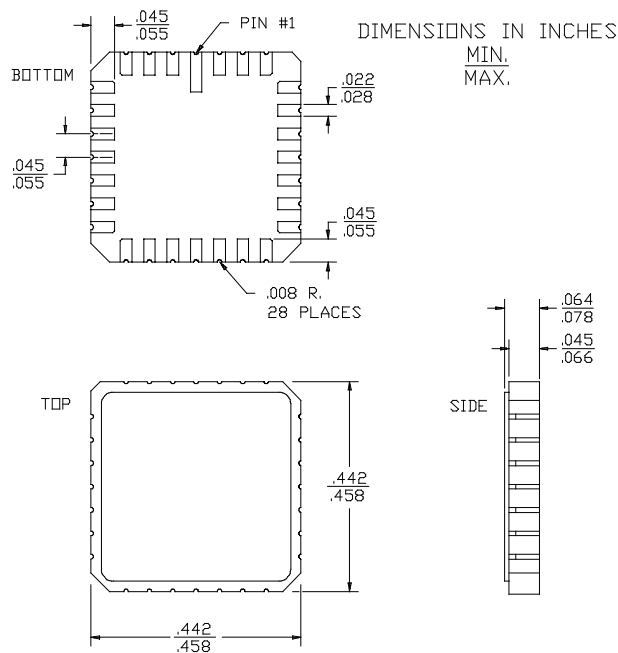
14. Minimum limits are specified but not tested on Propagation Delays.

15. See "Parameter Measurement Information" in the General Information Section.

**Ordering Information**

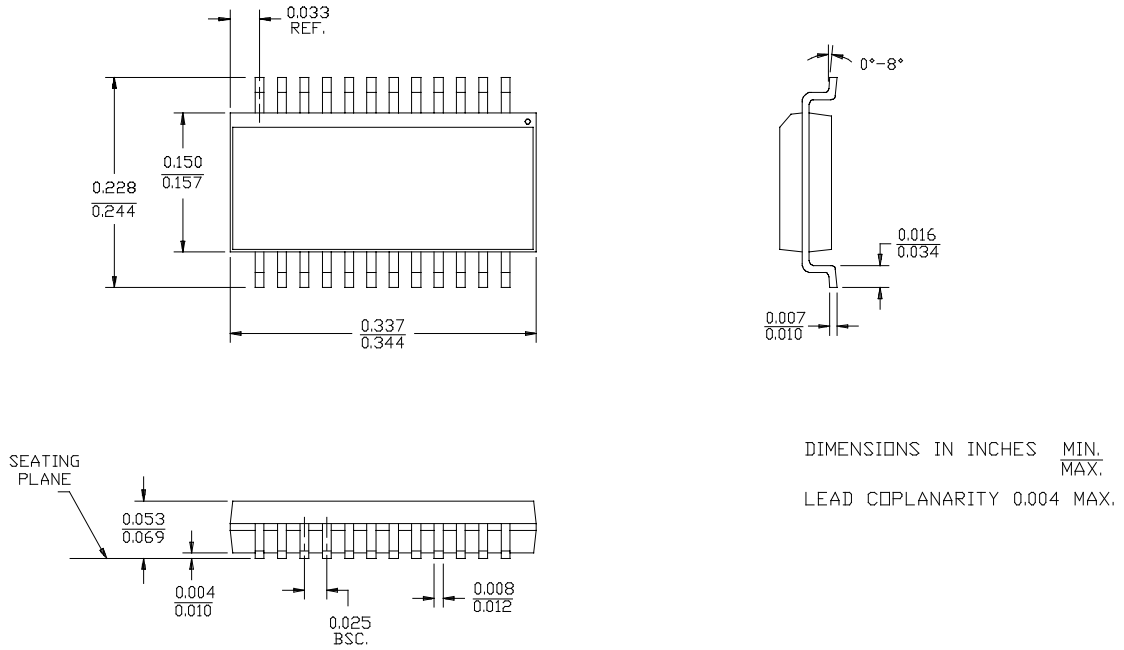
Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
5.4	CY74FCT646CTQCT	Q13	24-Lead (150-Mil) QSOP	Commercial
	CY74FCT646CTSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	
6.0	CY54FCT646CTLMB	L64	28-Square Leadless Chip Carrier	Military
6.3	CY74FCT646ATQCT	Q13	24-Lead (150-Mil) QSOP	Commercial
	CY74FCT646ATSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	
9.0	CY74FCT646TQCT	Q13	24-Lead (150-Mil) QSOP	Commercial
	CY74FCT646TSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	
11.0	CY54FCT646TLMB	L64	28-Square Leadless Chip Carrier	Military

Document #: 38-00267-C

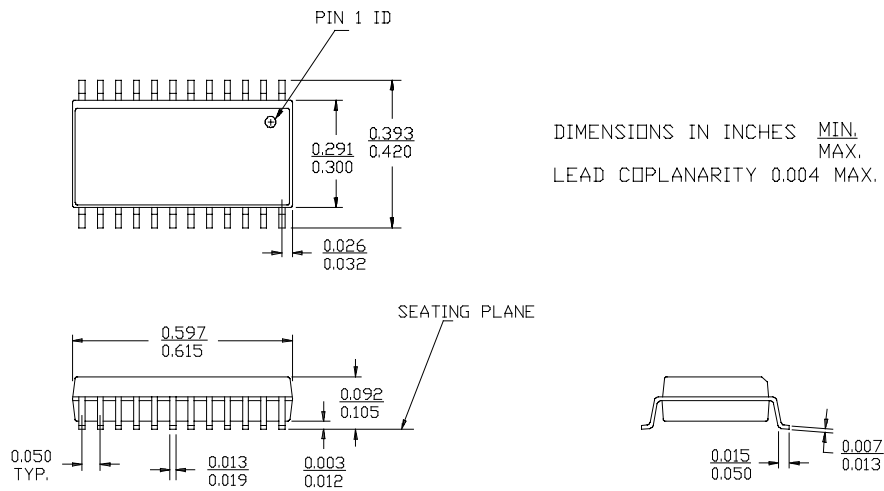
**Package Diagrams**
**28-Square Leadless Chip Carrier L64**  
 MIL-STD-1835 C-4


Package Diagrams (continued)

**24-Lead Quarter Size Outline Q13**



**24-Lead (300-Mil) Molded SOIC S13**



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